

R76PN3150SE30J

Aliases (76PN3150SE30J)

R76, Film, Double Metallized Polypropylene, Automotive Grade, 0.15 uF, 5%, 630 VDC, 85°C, 22.5mm



Click [here](#) for the 3D model.

Dimensions

L	26.5mm +0.3/-0.5mm
H	17mm +0.1/-0.5mm
T	8.5mm +0.2/-0.5mm
S	22.5mm +/-0.4mm
LL	4mm +2mm
F	0.8mm +/-0.05mm

Packaging Specifications

Packaging	Bulk, Bag
Packaging Quantity	468

General Information

Series	R76
Dielectric	Double Metallized Polypropylene
Style	Radial
Features	Automotive Grade, Pulse
RoHS	Yes
Termination	Cut (Tinned Wire)
Lead	Cut
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	4.4 g

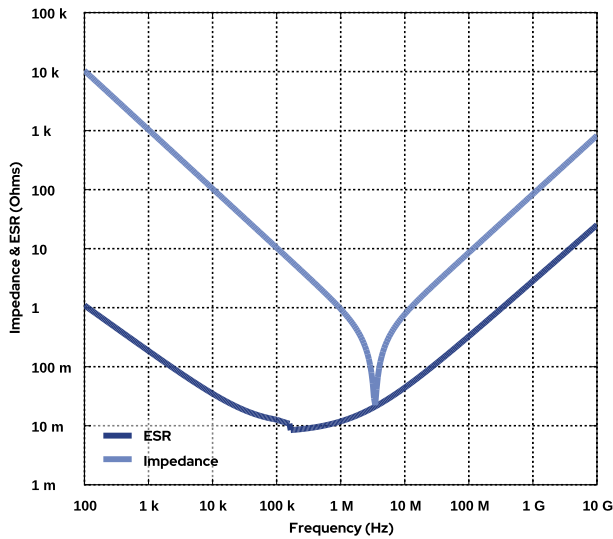
Specifications

Capacitance	0.15 uF
Capacitance Tolerance	5%
Voltage DC	630 VDC
Voltage AC	400 VAC
Temperature Range	-55/+110°C
Rated Temperature	85°C
Dissipation Factor	0.03% 1kHz, 0.06% 10kHz
Insulation Resistance	100 GOhms
Max dV/dt	1500 V/us
ESR	15.92 mOhms (100kHz)
Ripple Current	5.7 Amps (100kHz 85C), 225 Amps (Peak)
Inductance	16 nH

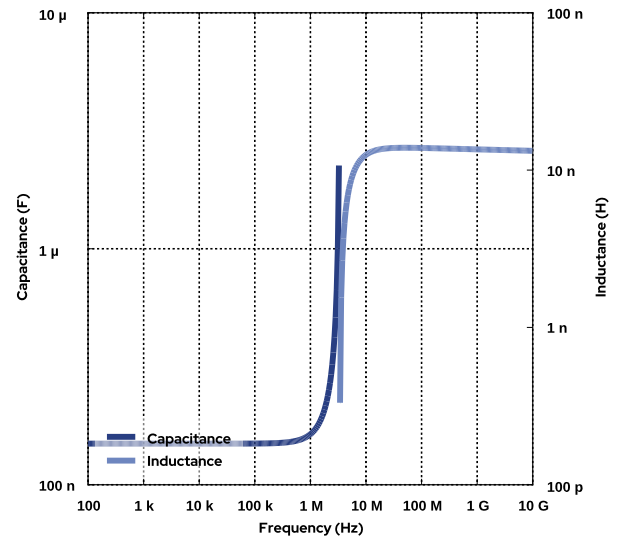
Simulations

For the complete simulation environment please visit [K-SIM](#).

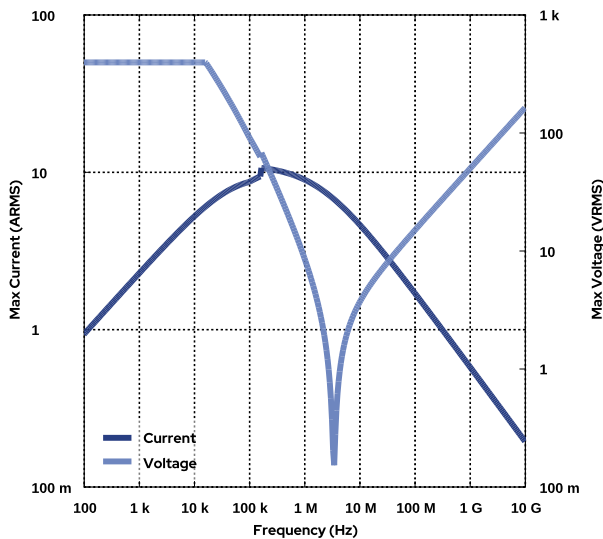
Impedance and ESR



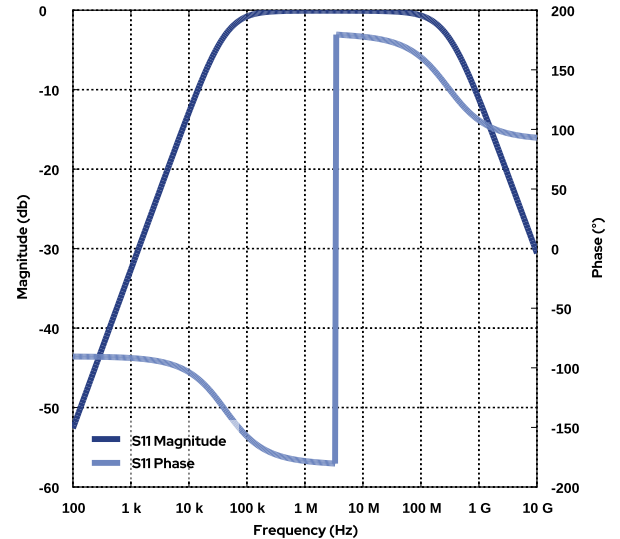
Capacitance and Inductance



Current and Voltage



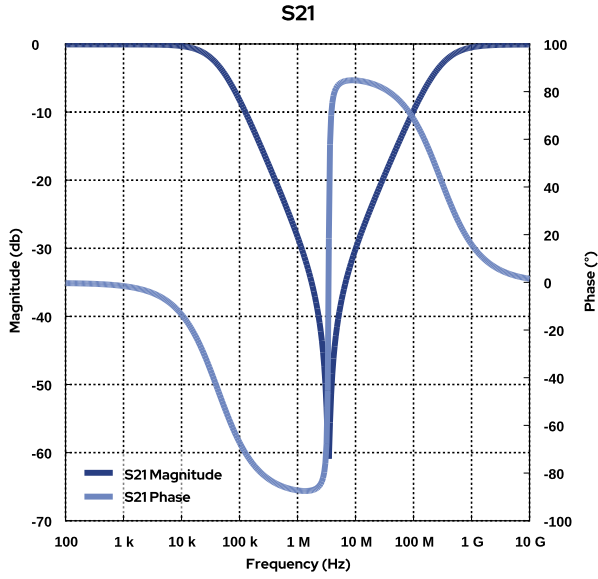
S11



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These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.
- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
- The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages generated at any other harmonics.
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.